

KSA1015GRBU

Request a Quote

KSA1015GRBU Information

	Part Number	KSA1015GRBU	
www.ibgisgner.com	Manufacturer	Fairchild/ON Semiconductor	
	Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single	
	Description	TRANS PNP 50V 0.15A TO-92	
l'and and and and and and and and and and	Package	TO-226-3, TO-92-3 (TO-226AA)	
		For the pricing/inventory/lead time, please contact	
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com	

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



KSA1015GRBU Specifications

Manufacturer Part NumberKSA1015GRBUManufacturerFairchild/ON SemiconductorCategoryDiscrete Semiconductor ProductsTransistor Selipolar (BJT) - SinglePackageTO-226-3, TO-92-3 (TO-226AA)Series-Transistor TypePNPCurrent - Collector (Ic) (Max)150mAVoltage - Collector Emitter Breakdown (Max)50VVce Saturation (Max) @ Ib, Ic300mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce200 @ 2mA, 6VPower - Max400mWFrequency - TransitionS0WHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO -226.3, TO-92.3 (TO-226AA)	
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Transistor TypePNPCurrent - Collector (Ic) (Max)150mAVoltage - Collector Emitter Breakdown (Max)50VVcc Saturation (Max) @ Ib, Ic300mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce200 @ 2mA, 6VPower - Max400mWFrequency - Transition80MHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTo-226-3, TO-92-3 (TO-226AA)	
Current - Collector (Ic) (Max)150mAVoltage - Collector Emitter Breakdown (Max)50VVce Saturation (Max) @ Ib, Ic300mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce200 @ 2mA, 6VPower - Max400mWFrequency - Transition80MHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)	
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DC Current Gain (hFE) (Min) @ Ic, Vce200 @ 2mA, 6VPower - Max400mWFrequency - Transition80MHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)	
Power - Max400mWFrequency - Transition80MHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-226AA)	
Frequency - Transition80MHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)	
Operating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)	
Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)	
Package / Case TO-226-3, TO-92-3 (TO-226AA)	
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Supplier Device Package TO-92-3	
Report	errors?

KSA1015GRBU Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

KSA1015GRBU Payment Methods



KSA1015GRBU Shipping Methods



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